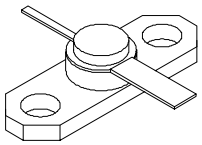
SGS-THOMSON MICROELECTRONICS

MSC80195

RF & MICROWAVE TRANSISTORS GENERAL PURPOSE LINEAR APPLICATIONS

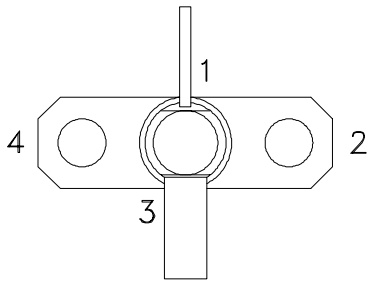
- EMITTER BALLASTED
- CLASS A LINEAR OPERATION
- COMMON EMITTER
- VSWR CAPABILITY 20:1 @ RATED CONDITIONS
- ft 3.2 GHz TYPICAL
- NOISE FIGURE 12.0 dB @ 2 GHz
- P_{OUT} = 28 dBm MIN. @ 2.0 GHz



.250 2LFL (S011)
hermetically sealed

ORDER CODE	BRANDING
MSC80195	80195

PIN CONNECTION



1. Collector
2. Emitter
3. Baser
4. Emitter

DESCRIPTION

The MSC80195 is a hermetically sealed NPN power transistor featuring a unique matrix structure. This device is specifically designed for Class A linear applications to provide high gain and high output power at the 1.0 dB compression point.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C)

Symbol	Parameter	Value	Unit
P_{DISS}	Power Dissipation (see Safe Area)	—	W
I_C	Device Bias Current	300	mA
V_{CE}	Collector-Emitter Bias Voltage*	20	V
T_J	Junction Temperature	200	°C
T_{STG}	Storage Temperature	– 65 to +200	°C

THERMAL DATA

$R_{TH(j-c)}$	Junction-Case Thermal Resistance*	35	°C/W

*Applies only to rated RF amplifier operation

ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

STATIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV_{CBO}	I_C = 1mA	I_E = 0mA	50	—	—	V
BV_{EBO}	I_E = 1mA	I_C = 0mA	3.5	—	—	V
BV_{CEO}	IC = 5mA	I_B = 0mA	20	—	—	V
I_{CEO}	V_{CE} = 18V		—	—	0.5	mA
h_{FE}	V_{CE} = 5V	I_C = 100mA	15	—	120	—

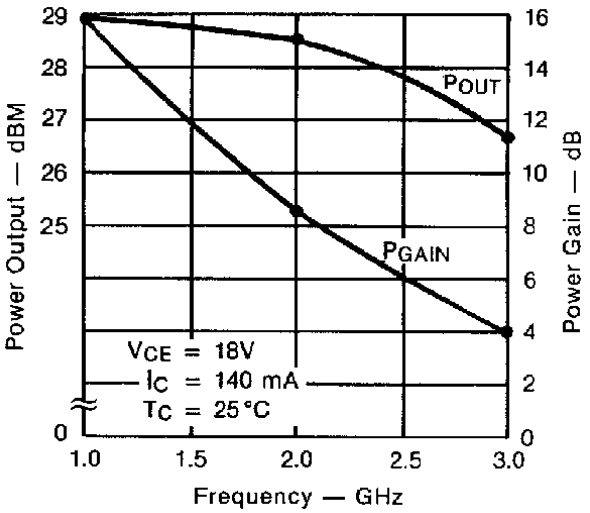
DYNAMIC

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
G_P*	f = 2.0 GHz	P_{OUT} = 28 dBm		—	—	1	dB
ΔG_P*	f = 2.0 GHz	P_{OUT} = 28 dBm	ΔP_{OUT} = 10 dB	7.5	8.5	—	dB
C_{OB}	f = 1 MHz	V_{CB} = 28 V		—	—	3.0	pF

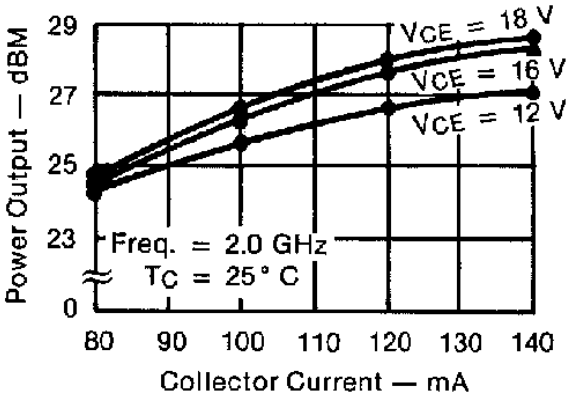
* Note: V_{CE} = 18 V
I_C = 140mA

TYPICAL PERFORMANCE

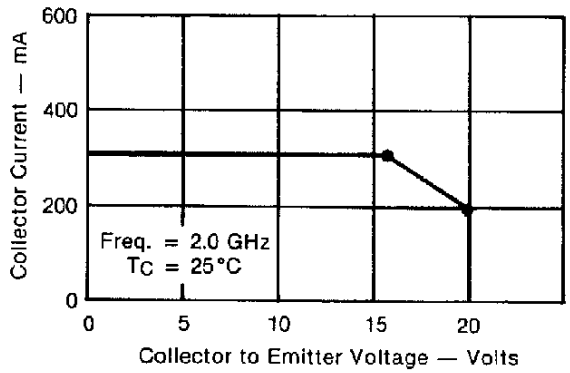
TYPICAL POWER OUTPUT & GAIN @ 1dB COMPRESSION POINT vs FREQUENCY



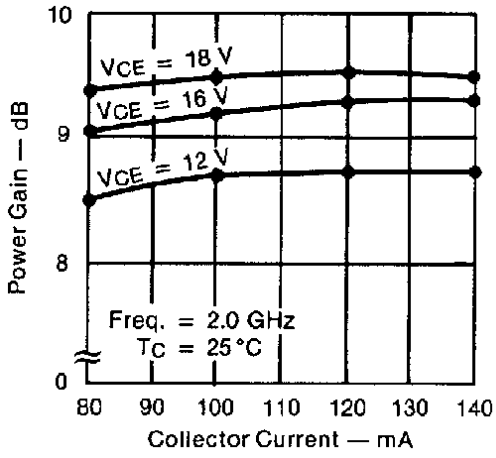
TYPICAL POWER OUTPUT & GAIN @ 1dB COMPRESSION POINT vs COLLECTOR CURRENT



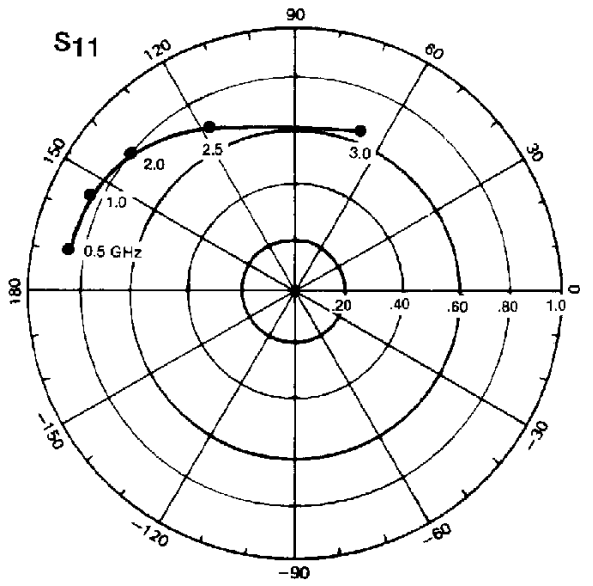
MAXIMUM OPERATING AREA FOR FORWARD BIAS OPERATION

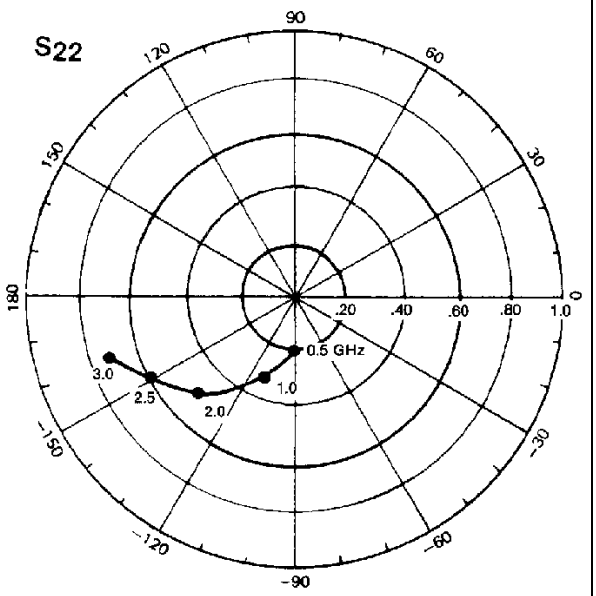


TYPICAL LINEAR GAIN vs COLLECTOR CURRENT

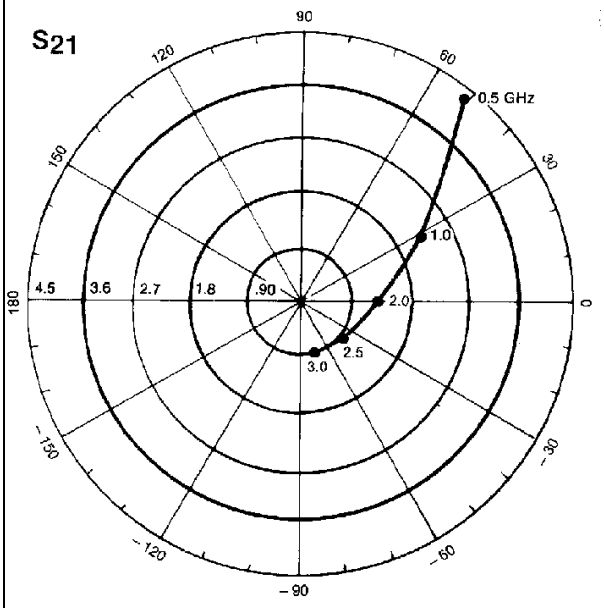


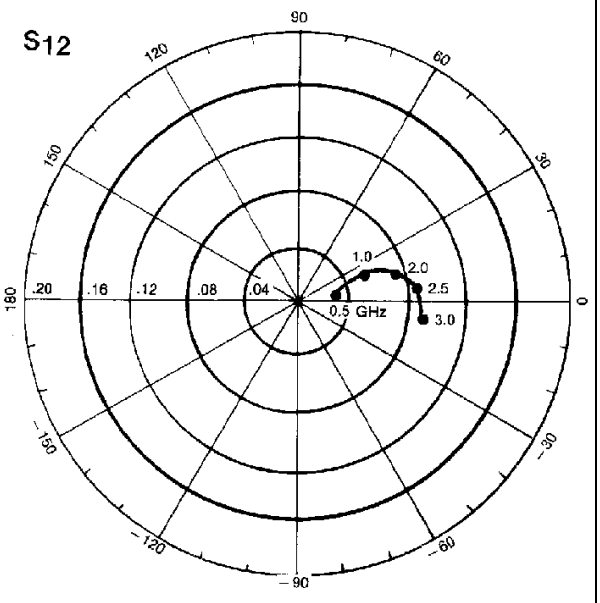
TYPICAL S–PARAMETERS





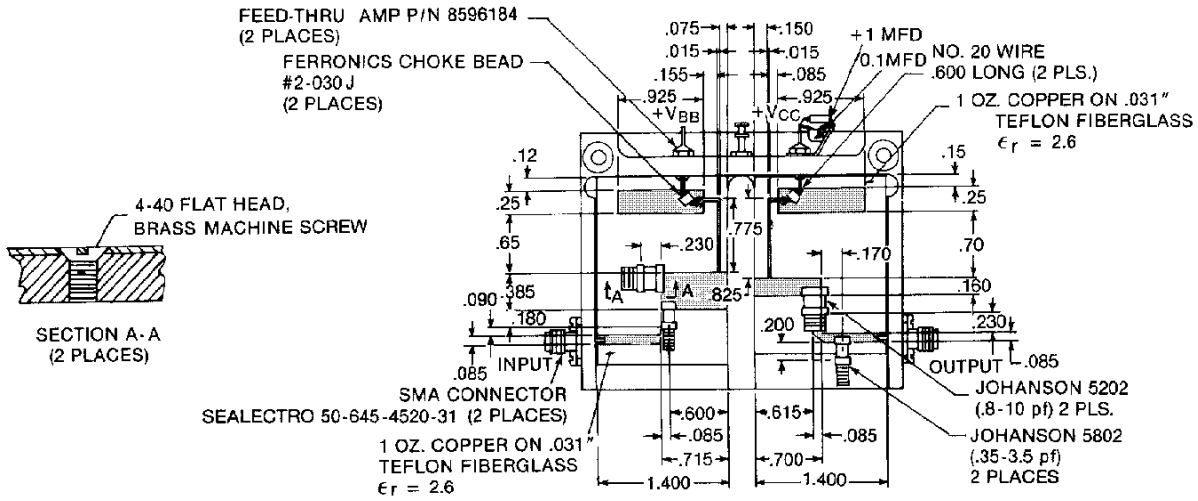
V_{CE} = 18 V
I_C = 140mA
Zg = 50 ohms





TEST CIRCUIT

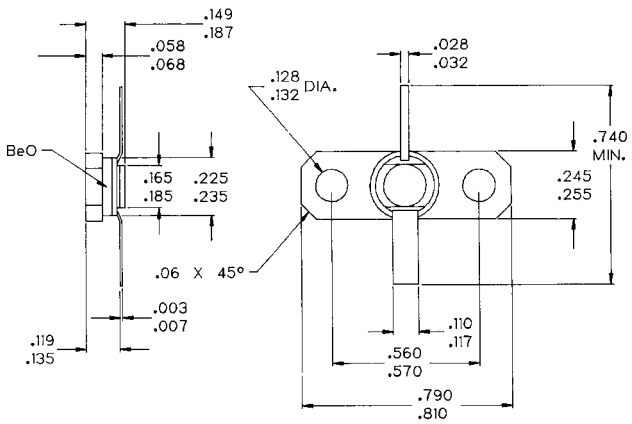
Ref.: Dwg. No. C127304A



All dimensions are in inches.

PACKAGE MECHANICAL DATA

Ref.: Dwg. No.: J135021C



NOTES:
1. ALL TOLERANCE ± .010 EXCEPT WHERE NOTED; DIMENSIONS IN INCHES.